







OPA991-Q1, OPA2991-Q1, OPA4991-Q1 SBOSA12F - MARCH 2020 - REVISED JUNE 2023

OPAx991-Q1 Automotive, 40-V Rail-to-Rail Input or Output, Low Offset Voltage, Low Noise Op Amp

1 Features

- AEC-Q100 qualified for automotive applications
 - Temperature grade 1: –40°C to +125°C, T_A
 - Device HBM ESD classification level 2A
 - Device CDM ESD classification level C6
- Low offset voltage: ±125 μV
- Low offset voltage drift: ±0.3 µV/°C
- Low noise: 10.8 nV/√Hz at 1 kHz
- High common-mode rejection: 130 dB
- Low bias current: ±10 pA
- Rail-to-rail input and output
- Wide bandwidth: 4.5 MHz GBW
- High slew rate: 21 V/µs
- High capacitive load drive: 1 nF
- MUX-friendly/comparator inputs
 - Amplifier operates with differential inputs up to supply rail
 - Amplifier can be used in open-loop or as comparator
- Low quiescent current: 560 µA per amplifier
- Wide supply: ± 1.35 V to ± 20 V, 2.7 V to 40 V
- Robust EMIRR performance: EMI/RFI filters on input and supply pins

2 Applications

- Optimized for AEC-Q100 grade 1 applications
- Infotainment and cluster
- Passive safety
- Body electronics and lighting
- HEV/EV inverter and motor control
- On-board (OBC) and wireless charger
- Powertrain current sensor
- Advanced driver assistance systems (ADAS)
- High-side current sensing

3 Description

The OPAx991-Q1 family (OPA991-Q1, OPA2991-Q1, and OPA4991-Q1) is a family of high voltage (40 V) general purpose operational amplifiers for automotive application. These devices offer exceptional DC precision and AC performance, including rail-to-rail input or output, low offset (±125 µV, typical), low offset drift (±0.3 μ V/°C, typical), low noise (10.8 nV/ $\sqrt{\text{Hz}}$ and 1.8 μV_{PP}), and 4.5-MHz bandwidth.

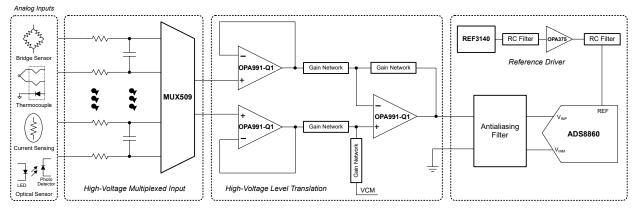
Unique features such as differential and commonmode input-voltage range to the supply rail, high output current (±75 mA), high slew rate (21 V/µs), and high capacitive load drive (1 nF) make the OPAx991-Q1 a robust, high-performance operational amplifier for high-voltage automotive applications.

The OPAx991-Q1 family of op amps is available in standard packages (such as SOT-23, SOIC, VSSOP, and TSSOP) and is specified from -40°C to 125°C.

Device Information

| PART NUMBER | CHANNEL COUNT | PACKAGE ⁽¹⁾ | BODY SIZE (NOM)(2) |
|-------------|---------------|------------------------|--------------------|
| OPA991-Q1 | Single | DBV (SOT-23, 5) | 2.90 mm × 1.60 mm |
| | | DGK (VSSOP, 8) | 3.00 mm × 3.00 mm |
| OPA2991-Q1 | Dual | PW (TSSOP, 8) | 3.00 mm × 4.40 mm |
| | | | 4.90 mm × 3.90 mm |
| | | DYY (SOT-23, 14) | 4.20 mm × 2.00 mm |
| OPA4991-Q1 | Quad | PW (TSSOP, 14) | 5.00 mm × 4.40 mm |
| | | D (SOIC, 14) | 8.65 mm × 3.90 mm |

- For all available packages, see the orderable addendum at the end of the data sheet.
- The body size (length × width) is a nominal value and does not include pins.



OPAx991-Q1 in a High-Voltage Signal Chain



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4 Revision History

| NOT | E: Page numbers for previous revisions may differ from page numbers in the current version. | |
|------|--|------|
| | 2.1 age names of previous revisions may amor nom page names of mane carrent version. | |
| Cha | nges from Revision E (April 2023) to Revision F (June 2023) | Page |
| • C | Changed the status of the TSSOP (8) package from: preview to: active | 1 |
| • U | Jpdated the format of the <i>Device Information</i> table | 1 |
| Cha | nges from Revision D (September 2021) to Revision E (April 2023) | Page |
| • A | Added the TSSOP (8) package in <i>Package Information</i> table | |
| Cha | nges from Revision C (May 2021) to Revision D (September 2021) | Page |
| • D | Deleted preview note from SOIC (14) package in Device Information table | 1 |
| | Deleted preview note from SOT-23 (14) package in Device Information table | |
| • D | Deleted preview note from SOIC (8) package in Device Information table | 1 |
| • D | Deleted preview note from SOT-23 (5) package in <i>Device Information</i> table | 1 |
| | nges from Revision B (March 2021) to Revision C (May 2021) | Page |
| • D | Deleted preview note from TSSOP (14) package in <i>Device Information</i> table | 1 |
| Cha | nges from Revision A (December 2020) to Revision B (March 2021) | Page |
| • C | Changed data sheet status from "Advance Information" to "Production Data" | 1 |
| | Deleted preview note from VSSOP (8) package in Device Information table | |
| Char | nges from Revision * (March 2020) to Revision A (December 2020) | Page |
| | , , , , , , , | |
| | Jpdated the numbering format for tables, figures, and cross-references throughout the document. Added link to all applications in <i>Applications</i> section | |
| | Deleted SOT-23 (8) package from <i>Device Information</i> in the <i>Description</i> section | |
| | Added SOT-23 (14) package to <i>Device Information</i> in the <i>Description</i> section | |
| | Deleted Table of Graphs from the <i>Specifications</i> section | |
| ٠ ل | releted Table of Graphs Hottl the Specifications section | 10 |
| | | |



5 Pin Configuration and Functions

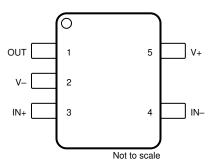


Figure 5-1. OPA991-Q1 DBV Package, 5-Pin SOT-23 (Top View)

Table 5-1. Pin Functions: OPA991-Q1

| P | PIN | TYPE ⁽¹⁾ | DESCRIPTION | |
|------|-----|---------------------|---------------------------------|--|
| NAME | NO. | ITPE | DESCRIPTION | |
| IN+ | 3 | I | Noninverting input | |
| IN- | 4 | I | Inverting input | |
| OUT | 1 | 0 | Output | |
| V+ | 5 | _ | Positive (highest) power supply | |
| V- | 2 | _ | Negative (lowest) power supply | |

(1) I = input, O = output



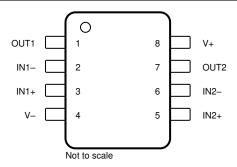


Figure 5-2. OPA2991-Q1 D, PW, and DGK Package, 8-Pin SOIC, TSSOP, and VSSOP (Top View)

Table 5-2. Pin Functions: OPA2991-Q1

| PIN | | TYPE ⁽¹⁾ | DESCRIPTION | |
|------|-----|---------------------------------|---------------------------------|--|
| NAME | NO. | ITPE | DESCRIPTION | |
| IN1+ | 3 | I Noninverting input, channel 1 | | |
| IN2+ | 5 | I | Noninverting input, channel 2 | |
| IN1- | 2 | I | Inverting input, channel 1 | |
| IN2- | 6 | I | Inverting input, channel 2 | |
| OUT1 | 1 | 0 | Output, channel 1 | |
| OUT2 | 7 | 0 | Output, channel 2 | |
| V+ | 8 | _ | Positive (highest) power supply | |
| V- | 4 | _ | Negative (lowest) power supply | |

(1) I = input, O = output



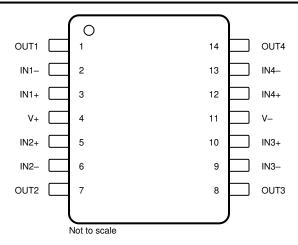


Figure 5-3. OPA4991-Q1 D, DYY, and PW Package, 14-Pin SOIC, SOT-23, and TSSOP (Top View)

Table 5-3. Pin Functions: OPA4991-Q1

| ı | PIN | | |
|------|-----|---------------------|---------------------------------|
| NAME | NO. | TYPE ⁽¹⁾ | DESCRIPTION |
| IN1+ | 3 | I | Noninverting input, channel 1 |
| IN1- | 2 | 1 | Inverting input, channel 1 |
| IN2+ | 5 | 1 | Noninverting input, channel 2 |
| IN2- | 6 | 1 | Inverting input, channel 2 |
| IN3+ | 10 | I | Noninverting input, channel 3 |
| IN3- | 9 | I | Inverting input, channel 3 |
| IN4+ | 12 | I | Noninverting input, channel 4 |
| IN4- | 13 | 1 | Inverting input, channel 4 |
| OUT1 | 1 | 0 | Output, channel 1 |
| OUT2 | 7 | 0 | Output, channel 2 |
| OUT3 | 8 | 0 | Output, channel 3 |
| OUT4 | 14 | 0 | Output, channel 4 |
| V+ | 4 | _ | Positive (highest) power supply |
| V- | 11 | _ | Negative (lowest) power supply |

⁽¹⁾ I = input, O = output



6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) (1)

| | | MIN | MAX | UNIT |
|---------------------------------------|--------------------------|------------|----------------------|------|
| Supply voltage, $V_S = (V+) -$ | (V-) | 0 | 42 | V |
| | Common-mode voltage (3) | (V-) - 0.5 | (V+) + 0.5 | V |
| Signal input pins | Differential voltage (3) | | V _S + 0.2 | V |
| | Current (3) | -10 | 10 | mA |
| Output short-circuit (2) | | Continuo | uous | |
| Operating ambient temperat | ture, T _A | -55 | 150 | °C |
| Junction temperature, T _J | | | 150 | °C |
| Storage temperature, T _{stg} | | -65 | 150 | °C |

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Short-circuit to ground, one amplifier per package. This device has been designed to limit *electrical* damage due to excessive output current, but extended short-circuit current, especially with higher supply voltage, can cause excessive heating and eventual *thermal* destruction. See the *Thermal Protection* section for more information.
- (3) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--|--|---|-------|------|
| V _(ESD) Electrostatic discharge | Electrostatic discharge | Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±2000 | V |
| | Charged-device model (CDM), per AEC Q100-011 | ±1000 | V | |

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|----------------|-------------------------------|------------|------------|------|
| Vs | Supply voltage, (V+) – (V–) | 2.7 | 40 | V |
| VI | Input voltage range | (V-) - 0.1 | (V+) + 0.1 | V |
| T _A | Specified ambient temperature | -40 | 125 | °C |

6.4 Thermal Information for Single Channel

| | THERMAL METRIC (1) | | |
|-----------------------|--|--------|------|
| | | | UNIT |
| | | 5 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 187.4 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 86.2 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 54.6 | °C/W |
| ΨЈТ | Junction-to-top characterization parameter | 27.8 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 54.3 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | °C/W |

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



6.5 Thermal Information for Dual Channel

| THERMAL METRIC ⁽¹⁾ | | | OPA2991-Q1 | | |
|-------------------------------|--|-------------|---------------|----------------|------|
| | | D (SOIC) | PW (TSSOP) | DGK (VSSOP) | UNIT |
| | | 8 PINS | 8 PINS | 8 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 132.6 | 185.1 | 176.5 | °C/W |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 73.4 | 74.0 | 68.1 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 76.1 | 115.7 | 98.2 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 24.0 | 12.3 | 12.0 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 75.4 | 114.0 | 96.7 | °C/W |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | N/A | N/A | °C/W |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.6 Thermal Information for Quad Channel

| THERMAL METRIC ⁽¹⁾ | | | OPA4991-Q1 | | | |
|-------------------------------|--|-------------|---------------|-----------------|------|--|
| | | D (SOIC) | PW (TSSOP) | DYY (SOT-23) | UNIT | |
| | | 14 PINS | 14 PINS | 14 PINS | | |
| R _{0JA} | Junction-to-ambient thermal resistance | 101.4 | 118.0 | 110.7 | °C/W | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 57.6 | 47.6 | 55.9 | °C/W | |
| R _{0JB} | Junction-to-board thermal resistance | 57.3 | 60.9 | 35.3 | °C/W | |
| Ψлт | Junction-to-top characterization parameter | 18.5 | 6.0 | 2.3 | °C/W | |
| ΨЈВ | Junction-to-board characterization parameter | 56.9 | 60.4 | 35.1 | °C/W | |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | N/A | N/A | °C/W | |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



6.7 Electrical Characteristics

For V_S = (V+) – (V–) = 2.7 V to 40 V (±1.35 V to ±20 V) at T_A = 25°C, R_L = 10 k Ω connected to V_S / 2, V_{CM} = V_S / 2, and $V_{O\ UT}$ = V_S / 2, unless otherwise noted.

| | PARAMETER | TEST CONDIT | TIONS | MIN | TYP | MAX | UNIT | |
|----------------------|-----------------------------|--|---|------------|----------|------------|--------------------|--|
| OFFSET \ | /OLTAGE | | | | | | | |
| | l | V - V | | | ±125 | ±895 | / | |
| V _{OS} | Input offset voltage | $V_{CM} = V_{-}$ | T _A = -40°C to 125°C | | | ±925 | μV | |
| dV _{OS} /dT | Input offset voltage drift | | T _A = -40°C to 125°C | | ±0.3 | | μV/°C | |
| DCDD | Input offset voltage | V _{CM} = V-, V _S = 4 V to 40 V | T - 40°C t- 405°C | | ±0.3 | ±1 | \/\/ | |
| PSRR | versus power supply | $V_{CM} = V_{-}, V_{S} = 2.7 \text{ V to } 40 \text{ V}^{(2)}$ | $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}$ | | ±1 | ±5 | μV/V | |
| | Channel separation | f = 0 Hz | 1 | | 5 | | μV/V | |
| INPUT BIA | AS CURRENT | | | | | | | |
| I _B | Input bias current | | | | ±10 | | pA | |
| Ios | Input offset current | | | | ±10 | | pA | |
| NOISE | 1 | | | | | | | |
| _ | Input voltage noise | f = 0.1 Hz to 10 Hz | | | 1.8 | | μV_{PP} | |
| E _N | Input voltage noise | - U. | | | 0.3 | | μV_{RMS} | |
| Input voltage noise | f = 1 kHz | | | 10.8 | | | | |
| e _N | density | f = 10 kHz | | | 9.4 | | | |
| i _N | Input current noise | f = 1 kHz | | | 82 | | fA/√ Hz | |
| INPUT VO | LTAGE RANGE | | | | | | | |
| V _{CM} | Common-mode voltage range | | | (V-) - 0.1 | | (V+) + 0.1 | V | |
| | Common-mode rejection ratio | $V_S = 40 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) - 2 \text{ V} \text{ (Main input pair)}$ | | 107 | 130 | | | |
| CMRR | | $V_S = 4 \text{ V, (V-)} - 0.1 \text{ V} < V_{CM} < (V+) - 2 \text{ V (Main input pair)}$ | T _A = -40°C to 125°C | 82 | 100 | | dB | |
| Civilat | | $V_S = 2.7 \text{ V}, (V-) - 0.1 \text{ V} < V_{CM} < (V+) - 2 \text{ V} (Main input pair})^{(2)}$ | 1 _A = -40 0 to 123 0 | 75 | 95 | | | |
| | | $V_S = 2.7 \text{ V to } 40 \text{ V, (V+)} - 1 \text{ V < V}_{CM}$ < (V+) + 0.1 V (Aux input pair) | | | 85 | | | |
| INPUT CA | PACITANCE | | | | | | | |
| Z_{ID} | Differential | | | | 100 9 | | MΩ pF | |
| Z _{ICM} | Common-mode | | | | 6 1 | | TΩ pF | |
| OPEN-LO | OP GAIN | | | | | | | |
| | | $V_S = 40 \text{ V}, V_{CM} = V - (V -) + 0.1 \text{ V} < V_O < (V +) - 0.1 \text{ V}$ | | 120 | 145 | | | |
| | | $(V-) + 0.1 V < V_0 < (V+) - 0.1 V$ | $T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$ | | 142 | | | |
| Δ | Open-loop voltage gain | $V_S = 4 \text{ V}, V_{CM} = V - (V -) + 0.1 \text{ V} < V_O < (V +) - 0.1 \text{ V}$ | | 104 | 130 | | dB | |
| A _{OL} | Open-loop voltage gain | $(V-) + 0.1 V < V_O < (V+) - 0.1 V$ | T _A = -40°C to 125°C | | 125 | | uБ | |
| | | $V_S = 2.7 \text{ V}, V_{CM} = V_{-}$ $(V_{-}) + 0.1 \text{ V} < V_{O} < (V_{+}) - 0.1 \text{ V}^{(2)}$ | | 101 | 120 | | | |
| | | $(V-) + 0.1 V < V_O < (V+) - 0.1 V^{(2)}$ | T _A = -40°C to 125°C | | 118 | | | |



6.7 Electrical Characteristics (continued)

For V_S = (V+) – (V–) = 2.7 V to 40 V (±1.35 V to ±20 V) at T_A = 25°C, R_L = 10 k Ω connected to V_S / 2, V_{CM} = V_S / 2, and $V_{O\ UT}$ = V_S / 2, unless otherwise noted.

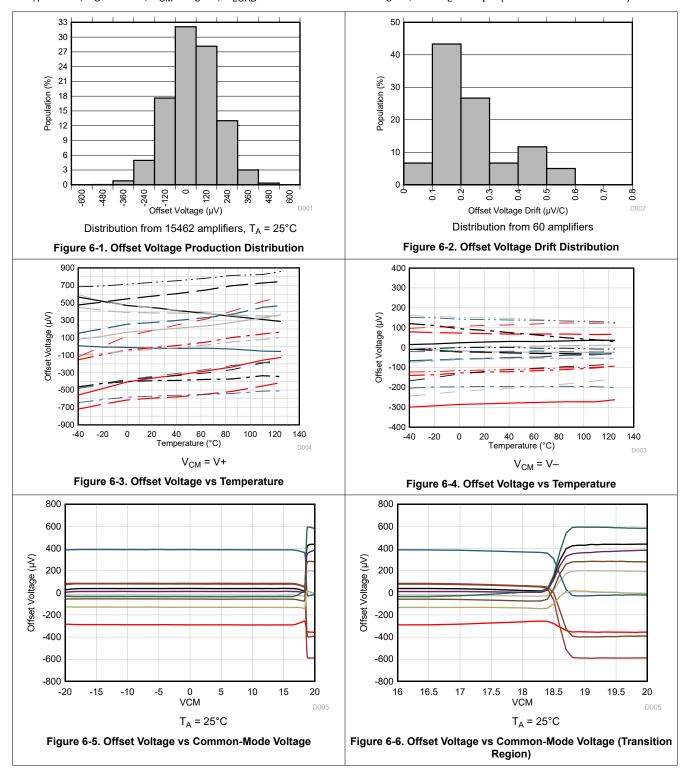
| *001 | PARAMETER | TEST CONDI | TIONS | MIN TYP | MAX | UNIT | |
|-------------------|---------------------------------------|--|---|----------|-----|------|--|
| FREQUE | NCY RESPONSE | | | | | | |
| GBW | Gain-bandwidth product | | | 4.5 | | MHz | |
| SR | Slew rate | V _S = 40 V, G = +1, C _L = 20 pF | | 21 | | V/µs | |
| | | To 0.01%, $V_S = 40 \text{ V}$, $V_{STEP} = 10 \text{ V}$, $V_{STEP} = 10 \text{ V}$ | G = +1, C _L = 20 pF | 2.5 | | | |
| | Settling time | To 0.01%, $V_S = 40 \text{ V}$, $V_{STEP} = 2 \text{ V}$, G | = +1, C _L = 20 pF | 1.5 | | μs | |
| t _S | Settling time | To 0.1%, $V_S = 40 \text{ V}$, $V_{STEP} = 10 \text{ V}$, G | = +1, C _L = 20 pF | 2 | | | |
| | | To 0.1%, $V_S = 40 \text{ V}$, $V_{STEP} = 2 \text{ V}$, $G = 10 \text{ V}$ | +1, C _L = 20 pF | 1 | | | |
| | Phase margin | $G = +1$, $R_L = 10$ kΩ, $C_L = 20$ pF | | 60 | | ٥ | |
| | Overload recovery time | V _{IN} × gain > V _S | | 400 | | ns | |
| THD+N | Total harmonic distortion + noise (1) | V _S = 40 V, V _O = 3 V _{RMS} , G = 1, f = 1 H | kHz | 0.00021% | | | |
| OUTPUT | | | - | | | | |
| | | | V _S = 40 V, R _L = no load ⁽²⁾ | 5 | 10 | | |
| | | | V _S = 40 V, R _L = 10 kΩ | 50 | 55 | | |
| | Voltage output swing from rail | Positive and negative rail headroom | $V_S = 40 \text{ V}, R_L = 2 \text{ k}\Omega$ | 200 | 250 | mV | |
| | | | V _S = 2.7 V, R _L = no load ⁽²⁾ | 1 | 6 | mv | |
| | | | $V_S = 2.7 \text{ V}, R_L = 10 \text{ k}\Omega$ | 5 | 12 | | |
| | | | $V_S = 2.7 \text{ V}, R_L = 2 \text{ k}\Omega$ | 25 | 40 | | |
| I _{SC} | Short-circuit current | | | ±75 | | mA | |
| C _{LOAD} | Capacitive load drive | | | 1000 | | pF | |
| Z _O | Open-loop output impedance | f = 1 MHz, I _O = 0 A | | 525 | | Ω | |
| POWER S | SUPPLY | | | | | | |
| | | V _{CM} = V-, I _O = 0 A | | 560 | 685 | | |
| | Quiescent current per | V _{CM} = V-, I _O = 0 A, (OPA991-Q1) | | 560 | 691 | | |
| IQ | amplifier | V _{CM} = V-, I _O = 0 A | - T _A = -40°C to 125°C | | 750 | μA | |
| | | V _{CM} = V-, I _O = 0 A, (OPA991-Q1) | 7 1A40 C 10 125 C | | 769 | | |

⁽¹⁾ Third-order filter; bandwidth = 80 kHz at -3 dB.

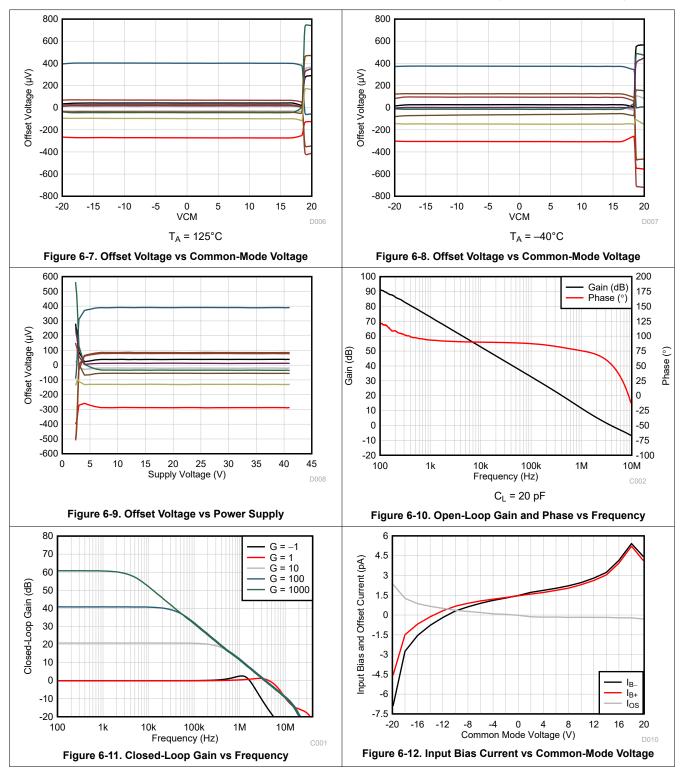
⁽²⁾ Specified by characterization only.



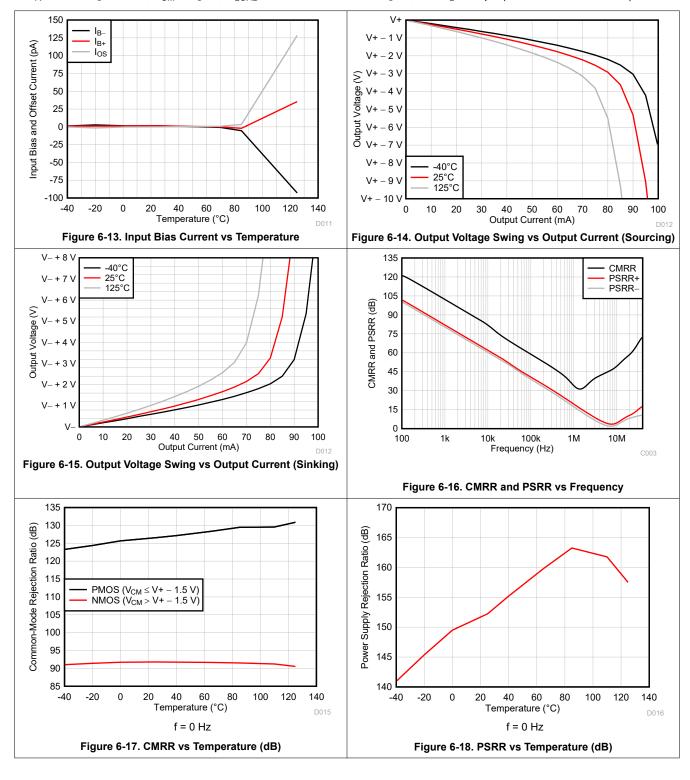
6.8 Typical Characteristics



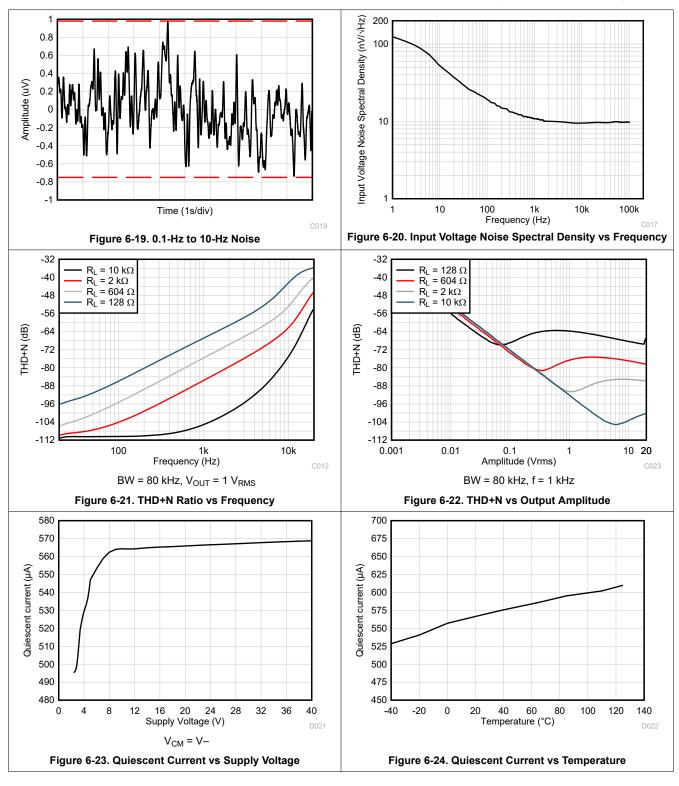




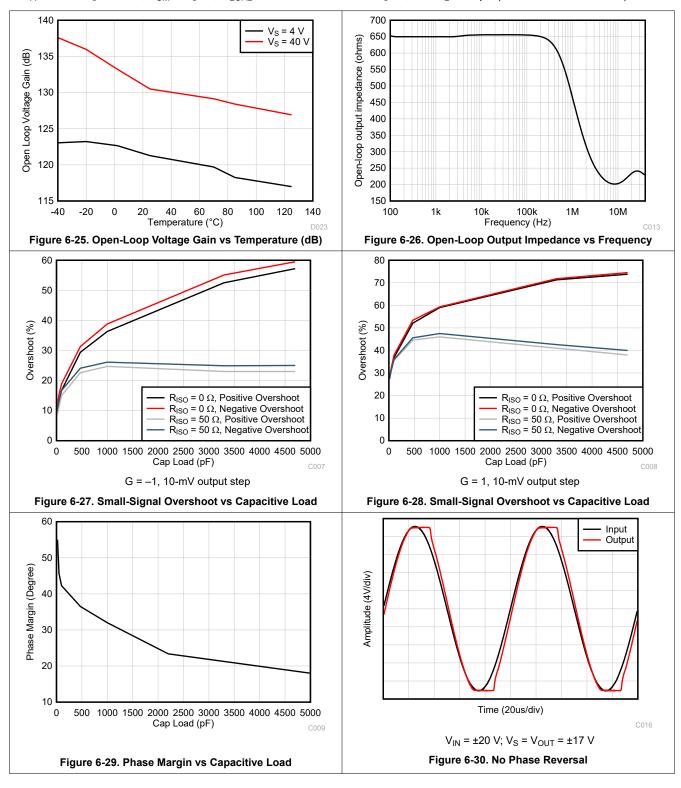




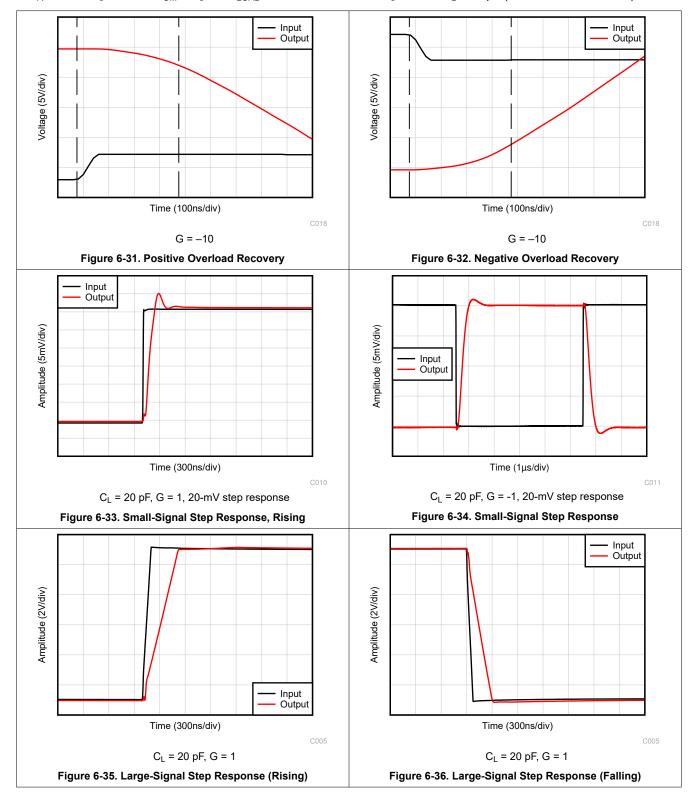




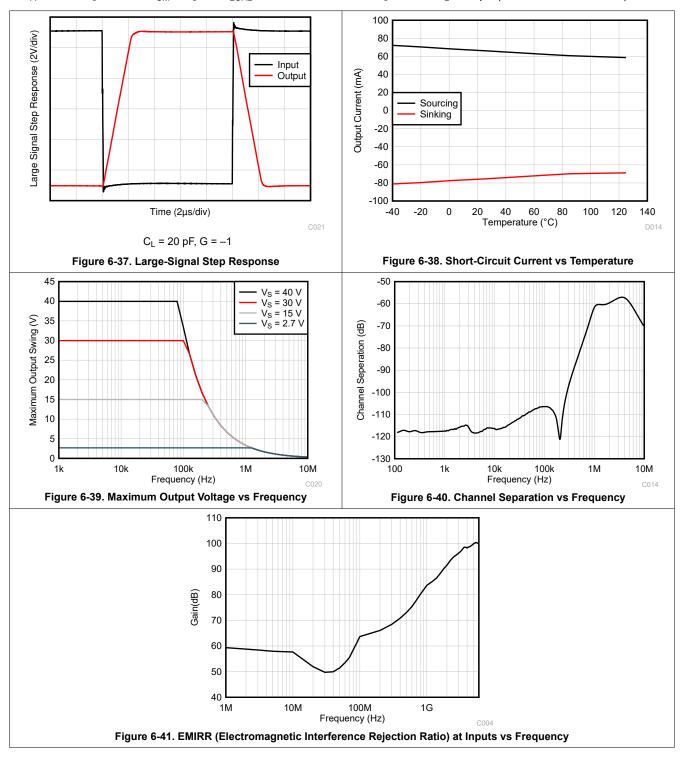












7 Detailed Description

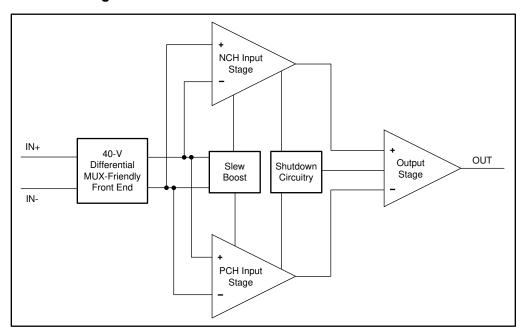
7.1 Overview

The OPAx991-Q1 family (OPA991-Q1, OPA2991-Q1, and OPA4991-Q1) is a new generation of 40-V general purpose operational amplifiers.

These devices offer excellent DC precision and AC performance, including rail-to-rail input or output, low offset $(\pm 125 \,\mu\text{V}, \text{typical})$, low offset drift $(\pm 0.3 \,\mu\text{V}/^{\circ}\text{C}, \text{typical})$, and 4.5-MHz bandwidth.

Unique features such as differential and common-mode input-voltage range to the supply rail, high output current (± 75 mA) and high slew rate (± 1 V/ μ s) make the OPAx991-Q1 a robust, high-performance operational amplifier for high-voltage automotive applications.

7.2 Functional Block Diagram





7.3 Feature Description

7.3.1 Input Protection Circuitry

The OPAx991-Q1 uses a unique input architecture to eliminate the requirement for input protection diodes but still provides robust input protection under transient conditions. Figure 7-1 shows conventional input diode protection schemes that are activated by fast transient step responses and introduce signal distortion and settling time delays because of alternate current paths, as shown in Figure 7-2. For low-gain circuits, these fast-ramping input signals forward-bias back-to-back diodes, causing an increase in input current and resulting in extended settling time.

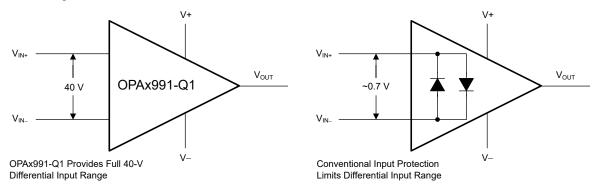


Figure 7-1. OPAx991-Q1 Input Protection Does Not Limit Differential Input Capability

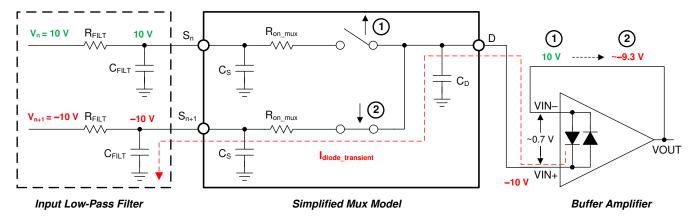


Figure 7-2. Back-to-Back Diodes Create Settling Issues

The OPAx991-Q1 family of operational amplifiers provides a true high-impedance differential input capability for high-voltage applications using a patented input protection architecture that does not introduce additional signal distortion or delayed settling time, making the device an optimal op amp for multichannel, high-switched, input applications. The OPAx991-Q1 tolerates a maximum differential swing (voltage between inverting and non-inverting pins of the op amp) of up to 40 V, making the device suitable for use as a comparator or in applications with fast-ramping input signals such as data-acquisition systems; see the TI TechNote MUX-Friendly Precision Operational Amplifiers for more information.

7.3.2 EMI Rejection

The OPAx991-Q1 uses integrated electromagnetic interference (EMI) filtering to reduce the effects of EMI from sources such as wireless communications and densely-populated boards with a mix of analog signal chain and digital components. EMI immunity can be improved with circuit design techniques; the OPAx991-Q1 benefits from these design improvements. Texas Instruments has developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. Figure 7-3 shows the results of this testing on the OPAx991-Q1. Table 7-1 lists the EMIRR IN+ values for the OPAx991-Q1 at particular frequencies commonly encountered in real-world applications.



The *EMI Rejection Ratio of Operational Amplifiers* application report contains detailed information on the topic of EMIRR performance as it relates to op amps and is available for download from www.ti.com.

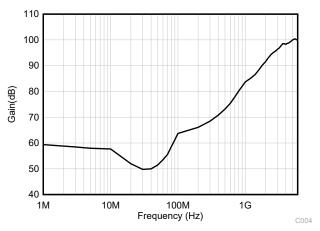


Figure 7-3. EMIRR Testing

Table 7-1. OPAx991-Q1 EMIRR IN+ for Frequencies of Interest

| FREQUENCY | APPLICATION OR ALLOCATION | EMIRR IN+ |
|-----------|--|-----------|
| 400 MHz | Mobile radio, mobile satellite, space operation, weather, radar, ultra-high frequency (UHF) applications | 73.2 dB |
| 900 MHz | Global system for mobile communications (GSM) applications, radio communication, navigation, GPS (to 1.6 GHz), GSM, aeronautical mobile, UHF applications | 82.5 dB |
| 1.8 GHz | GSM applications, mobile personal communications, broadband, satellite, L-band (1 GHz to 2 GHz) | 89.7 dB |
| 2.4 GHz | 802.11b, 802.11g, 802.11n, Bluetooth®, mobile personal communications, industrial, scientific and medical (ISM) radio band, amateur radio and satellite, S-band (2 GHz to 4 GHz) | 93.9 dB |
| 3.6 GHz | Radiolocation, aero communication and navigation, satellite, mobile, S-band | 95.7 dB |
| 5 GHz | 802.11a, 802.11n, aero communication and navigation, mobile communication, space and satellite operation, C-band (4 GHz to 8 GHz) | 98.0 dB |

7.3.3 Thermal Protection

The internal power dissipation of any amplifier causes its internal (junction) temperature to rise. This phenomenon is called *self heating*. The absolute maximum junction temperature of the OPAx991-Q1 is 150°C. Exceeding this temperature causes damage to the device. The OPAx991-Q1 has a thermal protection feature that reduces damage from self heating. The protection works by monitoring the temperature of the device and turning off the op amp output drive for temperatures above 170°C. Figure 7-4 shows an application example for the OPAx991-Q1 that has significant self heating because of its power dissipation (0.81 W). Thermal calculations indicate that for an ambient temperature of 65°C, the device junction temperature will reach 177°C. The actual device, however, turns off the output drive to recover towards a safe junction temperature. Figure 7-4 shows how the circuit behaves during thermal protection. During normal operation, the device acts as a buffer so the output is 3 V. When self heating causes the device junction temperature to increase above the internal limit, the thermal protection forces the output to a high-impedance state and the output is pulled to ground through resistor R_L. If the condition that caused excessive power dissipation is not removed, the amplifier will oscillate between a shutdown and enabled state until the output fault is corrected.

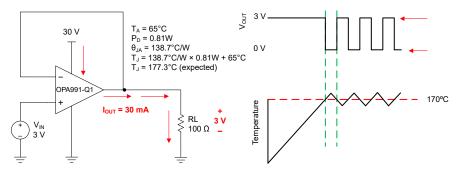


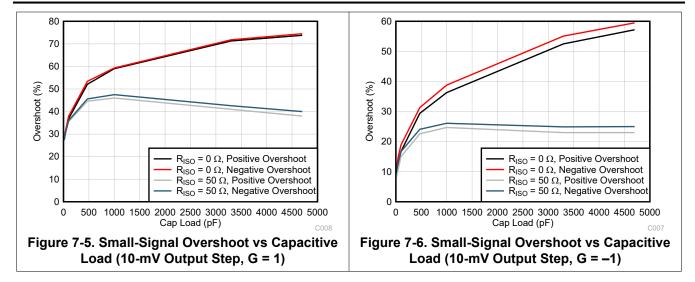
Figure 7-4. Thermal Protection

If the device continues to operate at high junction temperatures with high output power over a long period of time, regardless if the device is or is not entering thermal shutdown, the thermal dissipation of the device can slowly degrade performance of the device and eventually cause catastrophic destruction. Designers should be careful to limit output power of the device at high temperatures, or control ambient and junction temperatures under high output power conditions.

7.3.4 Capacitive Load and Stability

The OPAx991-Q1 features a resistive output stage capable of driving moderate capacitive loads, and by leveraging an isolation resistor, the device can easily be configured to drive large capacitive loads. Increasing the gain enhances the ability of the amplifier to drive greater capacitive loads; see Figure 7-5 and Figure 7-6. The particular op amp circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether an amplifier will be stable in operation.





For additional drive capability in unity-gain configurations, improve capacitive load drive by inserting a small resistor, $R_{\rm ISO}$, in series with the output, as shown in Figure 7-7. This resistor significantly reduces ringing and maintains DC performance for purely capacitive loads. However, if a resistive load is in parallel with the capacitive load, then a voltage divider is created, thus introducing a gain error at the output and slightly reducing the output swing. The error introduced is proportional to the ratio $R_{\rm ISO}$ / $R_{\rm L}$, and is generally negligible at low output levels. A high capacitive load drive makes the OPAx991-Q1 well suited for applications such as reference buffers, MOSFET gate drives, and cable-shield drives. The circuit shown in Figure 7-7 uses an isolation resistor, $R_{\rm ISO}$, to stabilize the output of an op amp. $R_{\rm ISO}$ modifies the open-loop gain of the system for increased phase margin.

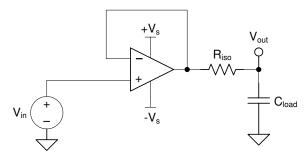


Figure 7-7. Extending Capacitive Load Drive With the OPAx991-Q1

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7.3.5 Common-Mode Voltage Range

The OPAx991-Q1 is a 40-V, true rail-to-rail input operational amplifier with an input common-mode range that extends 100 mV beyond either supply rail. This wide range is achieved with paralleled complementary N-channel and P-channel differential input pairs, as shown in Figure 7-8. The N-channel pair is active for input voltages close to the positive rail, typically (V+) - 1 V to 100 mV above the positive supply. The P-channel pair is active for inputs from 100 mV below the negative supply to approximately (V+) - 2 V. There is a small transition region, typically (V+) - 2 V to (V+) - 1 V in which both input pairs are on. This transition region can vary modestly with process variation, and within this region PSRR, CMRR, offset voltage, offset drift, noise, and THD performance may be degraded compared to operation outside this region.

Figure 6-5 shows this transition region for a typical device in terms of input voltage offset in more detail.

For more information on common-mode voltage range and PMOS/NMOS pair interaction, see *Op Amps With Complementary-Pair Input Stages* application note.

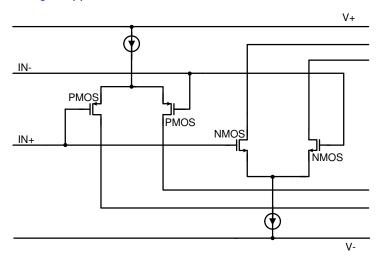


Figure 7-8. Rail-to-Rail Input Stage

7.3.6 Phase Reversal Protection

The OPAx991-Q1 family has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond its linear common-mode range. This condition is most often encountered in non-inverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The OPAx991-Q1 is a rail-to-rail input op amp; therefore, the common-mode range can extend beyond the rails. Input signals beyond the rails do not cause phase reversal; instead, the output limits into the appropriate rail. This performance is shown in Figure 7-9. For more information on phase reversal, see *Op Amps With Complementary-Pair Input Stages* application note.

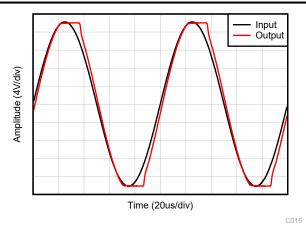


Figure 7-9. No Phase Reversal

7.3.7 Electrical Overstress

Designers often ask questions about the capability of an operational amplifier to withstand electrical overstress (EOS). These questions tend to focus on the device inputs, but may involve the supply voltage pins or even the output pin. Each of these different pin functions have electrical stress limits determined by the voltage breakdown characteristics of the particular semiconductor fabrication process and specific circuits connected to the pin. Additionally, internal electrostatic discharge (ESD) protection is built into these circuits to protect them from accidental ESD events both before and during product assembly.

Having a good understanding of this basic ESD circuitry and its relevance to an electrical overstress event is helpful. Figure 7-10 shows an illustration of the ESD circuits contained in the OPAx991-Q1 (indicated by the dashed line area). The ESD protection circuitry involves several current-steering diodes connected from the input and output pins and routed back to the internal power-supply lines, where the diodes meet at an absorption device or the power-supply ESD cell, internal to the operational amplifier. This protection circuitry is intended to remain inactive during normal circuit operation.

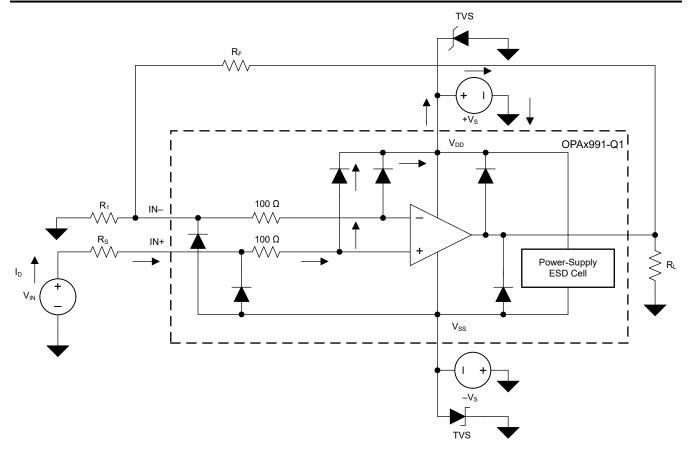


Figure 7-10. Equivalent Internal ESD Circuitry Relative to a Typical Circuit Application

An ESD event is very short in duration and very high voltage (for example; 1 kV, 100 ns), whereas an EOS event is long duration and lower voltage (for example; 50 V, 100 ms). The ESD diodes are designed for out-of-circuit ESD protection (that is, during assembly, test, and storage of the device before being soldered to the PCB). During an ESD event, the ESD signal is passed through the ESD steering diodes to an absorption circuit (labeled ESD power-supply circuit). The ESD absorption circuit clamps the supplies to a safe level.

Although this behavior is necessary for out-of-circuit protection, excessive current and damage is caused if activated in-circuit. A transient voltage suppressors (TVS) can be used to prevent against damage caused by turning on the ESD absorption circuit during an in-circuit ESD event. Using the appropriate current limiting resistors and TVS diodes allows for the use of device ESD diodes to protect against EOS events.

7.3.8 Overload Recovery

Overload recovery is defined as the time required for the op amp output to recover from a saturated state to a linear state. The output devices of the op amp enter a saturation region when the output voltage exceeds the rated operating voltage, either due to the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return back to the linear state. After the charge carriers return back to the linear state, the device begins to slew at the specified slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPAx991-Q1 is approximately 400 ns.

7.3.9 Typical Specifications and Distributions

Designers often have questions about a typical specification of an amplifier to design a more robust circuit. Due to natural variation in process technology and manufacturing procedures, every specification of an amplifier will exhibit some amount of deviation from the ideal value, like an amplifier's input offset voltage. These deviations often follow *Gaussian* (*bell curve*), or *normal* distributions, and circuit designers can leverage this information to guard band their system, even when there is not a minimum or maximum specification in the *Electrical Characteristics* table.

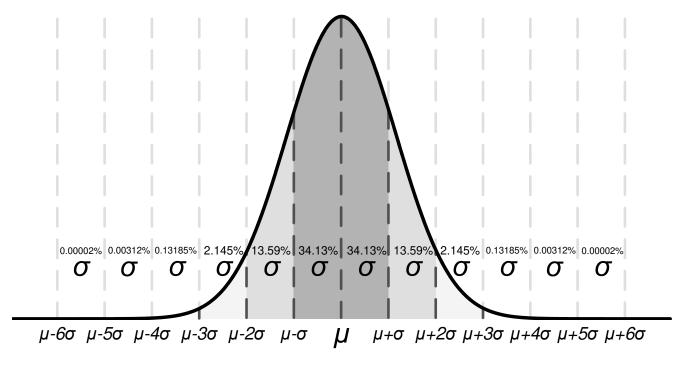


Figure 7-11. Ideal Gaussian Distribution

Figure 7-11 shows an example distribution, where μ , or mu, is the mean of the distribution, and where σ , or sigma, is the standard deviation of a system. For a specification that exhibits this kind of distribution, approximately two-thirds (68.26%) of all units can be expected to have a value within one standard deviation, or one sigma, of the mean (from $\mu - \sigma$ to $\mu + \sigma$).

Depending on the specification, values listed in the *typical* column of the *Electrical Characteristics* table are represented in different ways. As a general rule, if a specification naturally has a nonzero mean (for example, like gain bandwidth), then the typical value is equal to the mean (μ). However, if a specification naturally has a mean near zero (like input offset voltage), then the typical value is equal to the mean plus one standard deviation (μ + σ) to most accurately represent the typical value.



This chart can be used to calculate the approximate probability of a specification in a unit; for example, for OPAx991-Q1, the typical input voltage offset is 125 μ V, so 68.2% of all OPAx991-Q1 devices are expected to have an offset from –125 μ V to 125 μ V. At 4 σ (±500 μ V), 99.9937% of the distribution has an offset voltage less than ±500 μ V, which means 0.0063% of the population is outside of these limits, which corresponds to about 1 in 15,873 units.

Specifications with a value in the minimum or maximum column are assured by TI, and units outside these limits will be removed from production material. For example, the OPAx991-Q1 family has a maximum offset voltage of 895 μ V at 25°C, and even though this corresponds to more than 5 σ (\approx 1 in 1.7 million units), which is extremely unlikely, TI assures that any unit with larger offset than 895 μ V will be removed from production material.

For specifications with no value in the minimum or maximum column, consider selecting a sigma value of sufficient guard band for the application, and design worst-case conditions using this value. For example, the 6- σ value corresponds to about 1 in 500 million units, which is an extremely unlikely chance, and could be an option as a wide guard band to design a system around. In this case, the OPAx991-Q1 family does not have a maximum or minimum for offset voltage drift, but based on Figure 6-2 and the typical value of 0.3 μ V/°C in the *Electrical Characteristics* table, it can be calculated that the 6- σ value for offset voltage drift is about 1.8 μ V/°C. When designing for worst-case system conditions, this value can be used to estimate the worst possible offset across temperature without having an actual minimum or maximum value.

However, process variation and adjustments over time can shift typical means and standard deviations, and unless there is a value in the minimum or maximum specification column, TI cannot assure the performance of a device. This information should be used only to estimate the performance of a device.

7.4 Device Functional Modes

The OPAx991-Q1 has a single functional mode and is operational when the power-supply voltage is greater than $2.7 \text{ V } (\pm 1.35 \text{ V})$. The maximum power supply voltage for the OPAx991-Q1 is 40 V ($\pm 20 \text{ V}$).

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The OPAx991-Q1 family offers excellent DC precision and AC performance. These devices operate up to 40-V supply rails and offer true rail-to-rail input/output, low offset voltage and offset voltage drift, as well as 4.5-MHz bandwidth and high output drive. These features make the OPAx991-Q1 a robust, high-performance operational amplifier for high-voltage industrial applications.

8.2 Typical Applications

8.2.1 Low-Side Current Measurement

Figure 8-1 shows the OPAx991-Q1 configured in a low-side current sensing application. For a full analysis of the circuit shown in Figure 8-1 including theory, calculations, simulations, and measured data, see TI Precision Design TIPD129, *0-A to 1-A Single-Supply Low-Side Current-Sensing Solution*.

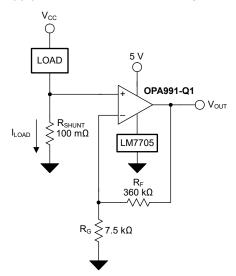


Figure 8-1. OPAx991-Q1 in a Low-Side, Current-Sensing Application

8.2.1.1 Design Requirements

The design requirements for this design are:

Load current: 0 A to 1 AOutput voltage: 4.9 V

Maximum shunt voltage: 100 mV



8.2.1.2 Detailed Design Procedure

The transfer function of the circuit in Figure 8-1 is given in Equation 1.

$$V_{OUT} = I_{LOAD} \times R_{SHUNT} \times Gain$$
 (1)

The load current (I_{LOAD}) produces a voltage drop across the shunt resistor (R_{SHUNT}). The load current is set from 0 A to 1 A. To keep the shunt voltage below 100 mV at maximum load current, the largest shunt resistor is defined using Equation 2.

$$R_{SHUNT} = \frac{V_{SHUNT_MAX}}{I_{LOAD\ MAX}} = \frac{100\ mV}{1\ A} = 100\ m\Omega \tag{2}$$

Using Equation 2, R_{SHUNT} is calculated to be 100 m Ω . The voltage drop produced by I_{LOAD} and R_{SHUNT} is amplified by the OPA991-Q1 to produce an output voltage of 0 V to 4.9 V. The gain needed by the OPA991-Q1 to produce the necessary output voltage is calculated using Equation 3.

$$Gain = \frac{(V_{OUT_MAX} - V_{OUT_MIN})}{(V_{IN_MAX} - V_{IN_MIN})}$$
(3)

Using Equation 3, the required gain is calculated to be 49 V/V, which is set with resistors R_F and R_G . Equation 4 is used to size the resistors, R_F and R_G , to set the gain of the OPA991-Q1 to 49 V/V.

$$Gain = 1 + \frac{(R_F)}{(R_G)} \tag{4}$$

Choosing R_F as 360 k Ω , R_G is calculated to be 7.5 k Ω . R_F and R_G were chosen as 360 k Ω and 7.5 k Ω because they are standard value resistors that create a 49:1 ratio. Other resistors that create a 49:1 ratio can also be used. Figure 8-2 shows the measured transfer function of the circuit shown in Figure 8-1.

8.2.1.3 Application Curve

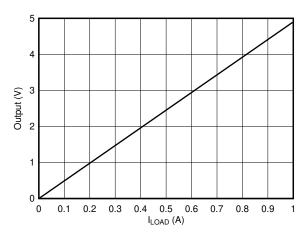


Figure 8-2. Low-Side, Current-Sense, Transfer Function

8.3 Power Supply Recommendations

The OPAx991-Q1 is specified for operation from 2.7 V to 40 V (±1.35 V to ±40 V); many specifications apply from –40°C to 125°C. Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in *Typical Characteristics*.

CAUTION

Supply voltages larger than 40 V can permanently damage the device; see the *Absolute Maximum Ratings*.

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, refer to *Layout*.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and op amp itself.
 Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-μF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for singlesupply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital
 and analog grounds paying attention to the flow of the ground current.
- In order to reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in Figure 8-4, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.
- Any precision integrated circuit may experience performance shifts due to moisture ingress into the plastic package. Following any aqueous PCB cleaning process, baking the PCB assembly is recommended to remove moisture introduced into the device packaging during the cleaning process. A low temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.



8.4.2 Layout Example

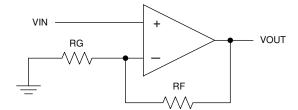


Figure 8-3. Schematic Representation

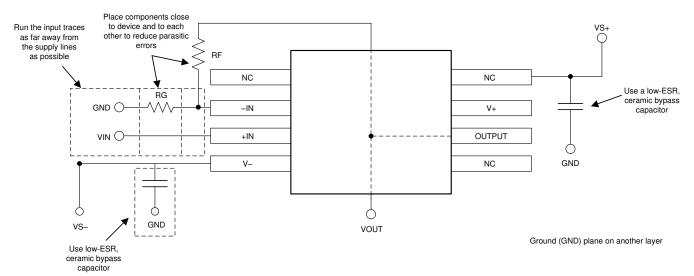


Figure 8-4. Operational Amplifier Board Layout for Noninverting Configuration



9 Device and Documentation Support

9.1 Device Support

9.1.1 Development Support

9.1.1.1 TINA-TI[™] (Free Software Download)

TINA™ is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI is a free, fully-functional version of the TINA software, preloaded with a library of macro models in addition to a range of both passive and active models. TINA-TI provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a free download from the Analog eLab Design Center, TINA-TI offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

Note

These files require that either the TINA software (from DesignSoft[™]) or TINA-TI software be installed. Download the free TINA-TI software from the TINA-TI folder.

9.1.1.2 TI Precision Designs

The OPAx991 is featured in several TI Precision Designs, available online at http://www.ti.com/ww/en/analog/precision-designs/. TI Precision Designs are analog solutions created by TI's precision analog applications experts and offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits.

9.2 Documentation Support

9.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Analog Engineer's Circuit Cookbook: Amplifiers solution guide
- Texas Instruments, AN31 Amplifier Circuit Collection application note
- Texas Instruments, MUX-Friendly Precision Operational Amplifiers application brief
- Texas Instruments, EMI Rejection Ratio of Operational Amplifiers application report
- Texas Instruments, Op Amps With Complementary-Pair Input Stages application note

9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.5 Trademarks

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9.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|-----------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| 00400040004004 | A OTIV (F | 1/0000 | DOI(| | 0500 | D 110 0 0 | (6) | 1 14 0000 1111 114 | 40.4.405 | OZDZ | |
| OPA2991QDGKRQ1 | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 27BT | Samples |
| OPA2991QDRQ1 | ACTIVE | SOIC | D | 8 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | O2991Q | Samples |
| OPA2991QPWRQ1 | ACTIVE | TSSOP | PW | 8 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | OPA291 | Samples |
| OPA4991QDRQ1 | ACTIVE | SOIC | D | 14 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | OP4991QD | Samples |
| OPA4991QDYYRQ1 | ACTIVE | SOT-23-THIN | DYY | 14 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | OPA4991Q | Samples |
| OPA4991QPWRQ1 | ACTIVE | TSSOP | PW | 14 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | O4991Q | Samples |
| OPA4991TQPWRQ1 | ACTIVE | TSSOP | PW | 14 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | O4991T | Samples |
| OPA991QDBVRQ1 | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2JAF | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

PACKAGE OPTION ADDENDUM

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF OPA2991-Q1, OPA4991-Q1, OPA991-Q1:

Catalog: OPA2991, OPA4991, OPA991

Enhanced Product : OPA4991-EP

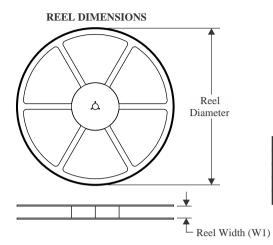
NOTE: Qualified Version Definitions:

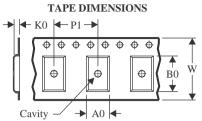
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications



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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

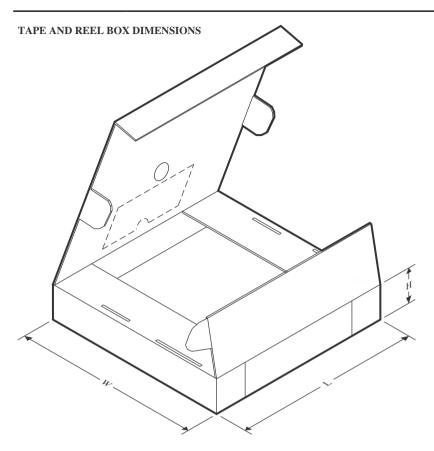


*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| OPA2991QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| OPA2991QDRQ1 | SOIC | D | 8 | 3000 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| OPA2991QPWRQ1 | TSSOP | PW | 8 | 3000 | 330.0 | 12.4 | 7.0 | 3.6 | 1.6 | 8.0 | 12.0 | Q1 |
| OPA4991QDRQ1 | SOIC | D | 14 | 3000 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| OPA4991QDYYRQ1 | SOT-23- THIN | DYY | 14 | 3000 | 330.0 | 12.4 | 4.8 | 3.6 | 1.6 | 8.0 | 12.0 | Q3 |
| OPA4991QPWRQ1 | TSSOP | PW | 14 | 3000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| OPA4991TQPWRQ1 | TSSOP | PW | 14 | 3000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| OPA991QDBVRQ1 | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |



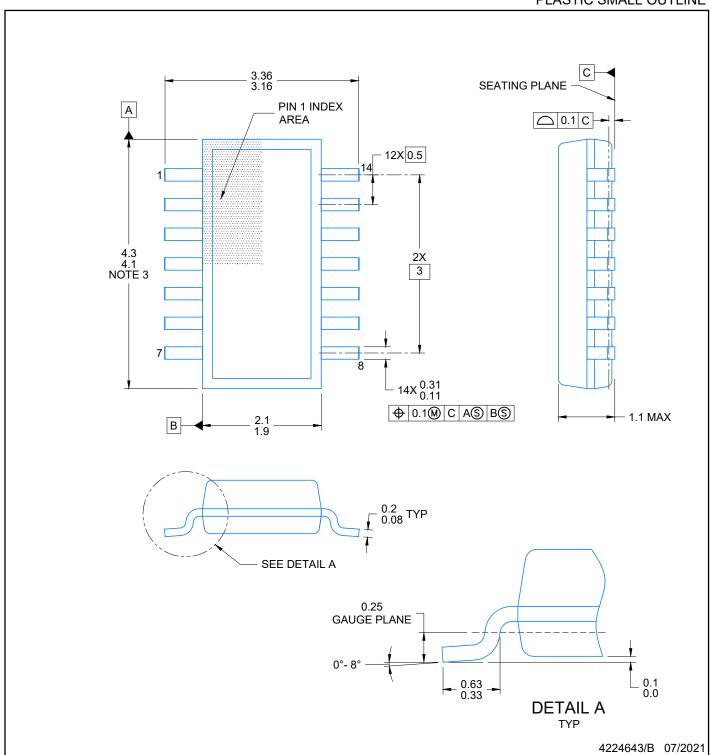
www.ti.com 29-Jun-2023



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA2991QDGKRQ1 | VSSOP | DGK | 8 | 2500 | 366.0 | 364.0 | 50.0 |
| OPA2991QDRQ1 | SOIC | D | 8 | 3000 | 356.0 | 356.0 | 35.0 |
| OPA2991QPWRQ1 | TSSOP | PW | 8 | 3000 | 356.0 | 356.0 | 35.0 |
| OPA4991QDRQ1 | SOIC | D | 14 | 3000 | 356.0 | 356.0 | 35.0 |
| OPA4991QDYYRQ1 | SOT-23-THIN | DYY | 14 | 3000 | 336.6 | 336.6 | 31.8 |
| OPA4991QPWRQ1 | TSSOP | PW | 14 | 3000 | 356.0 | 356.0 | 35.0 |
| OPA4991TQPWRQ1 | TSSOP | PW | 14 | 3000 | 356.0 | 356.0 | 35.0 |
| OPA991QDBVRQ1 | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |

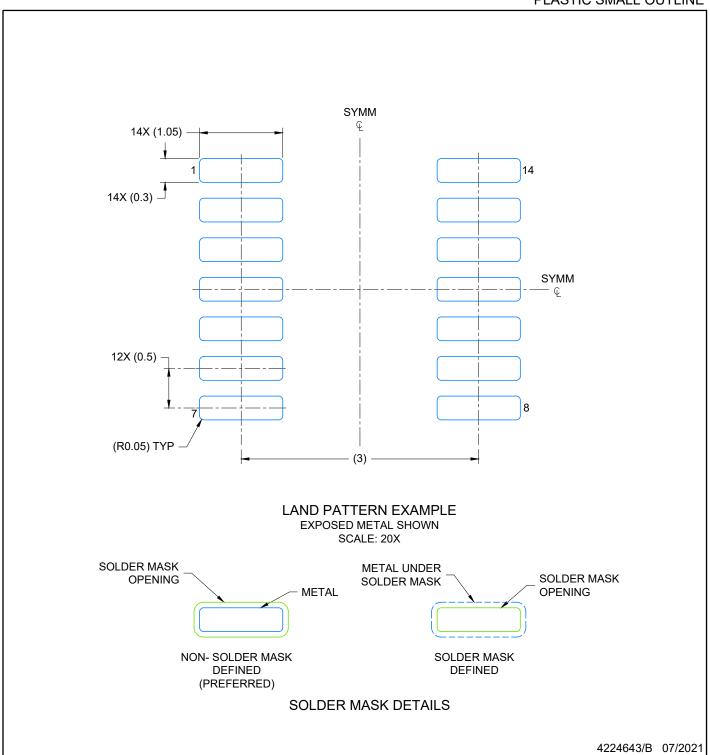
PLASTIC SMALL OUTLINE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- 5. Reference JEDEC Registration MO-345, Variation AB



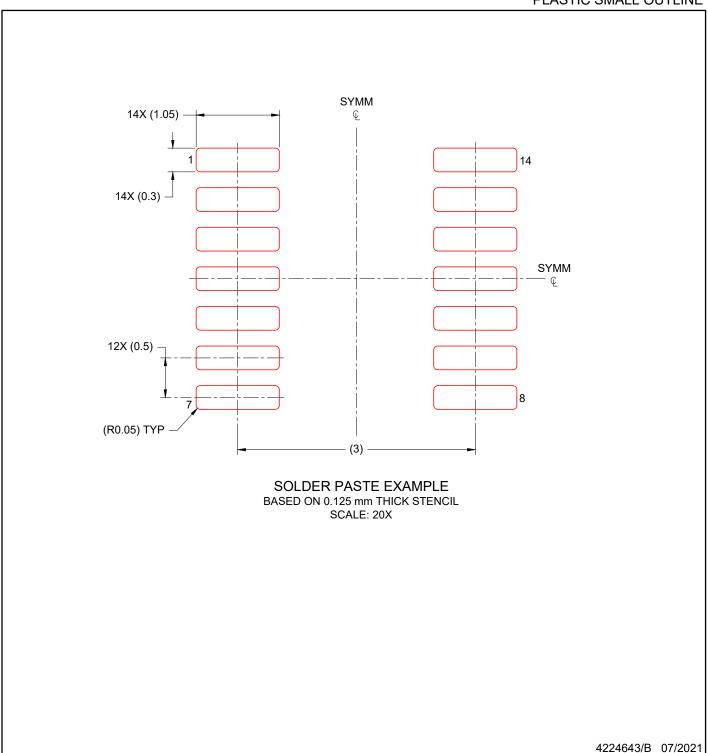
PLASTIC SMALL OUTLINE



- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE

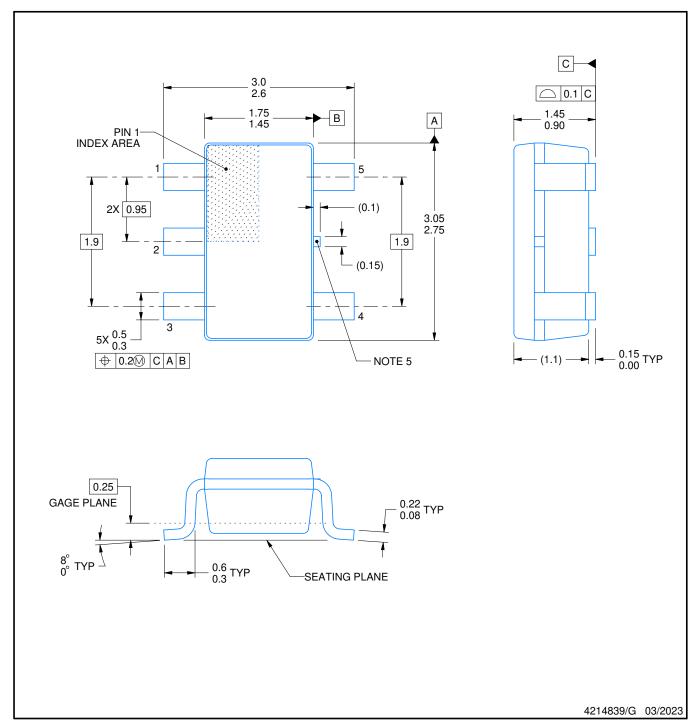


- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE TRANSISTOR

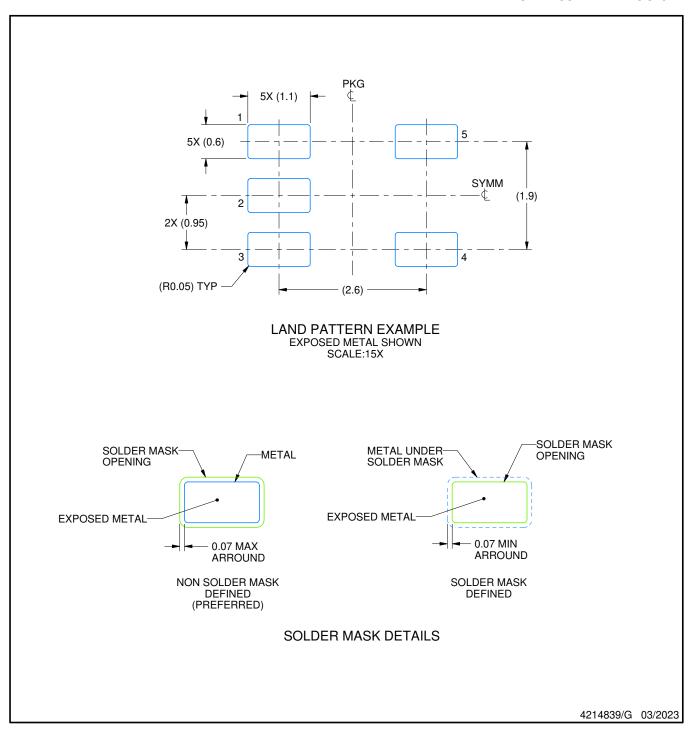


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR

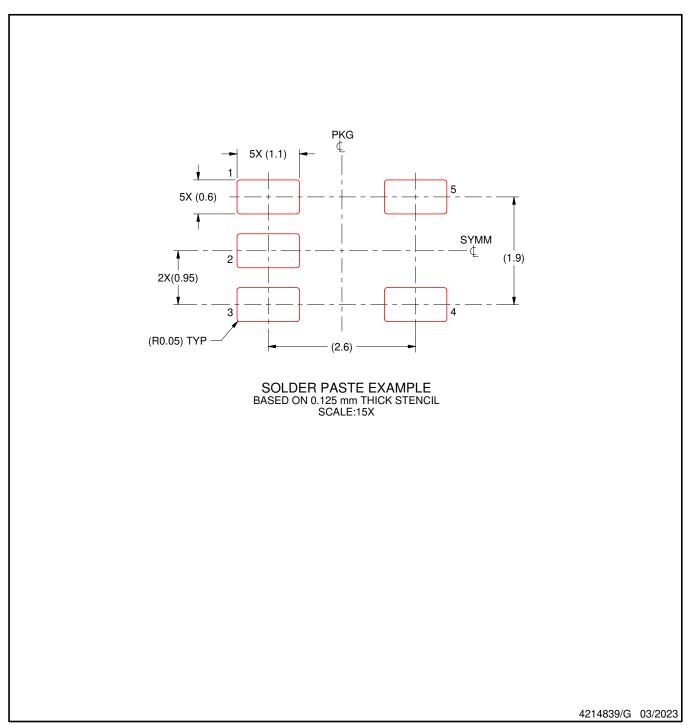


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE

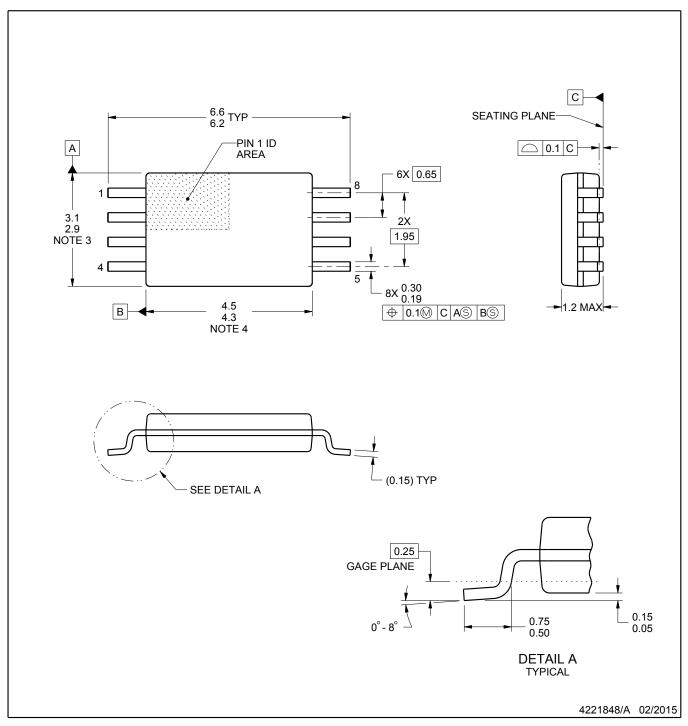


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



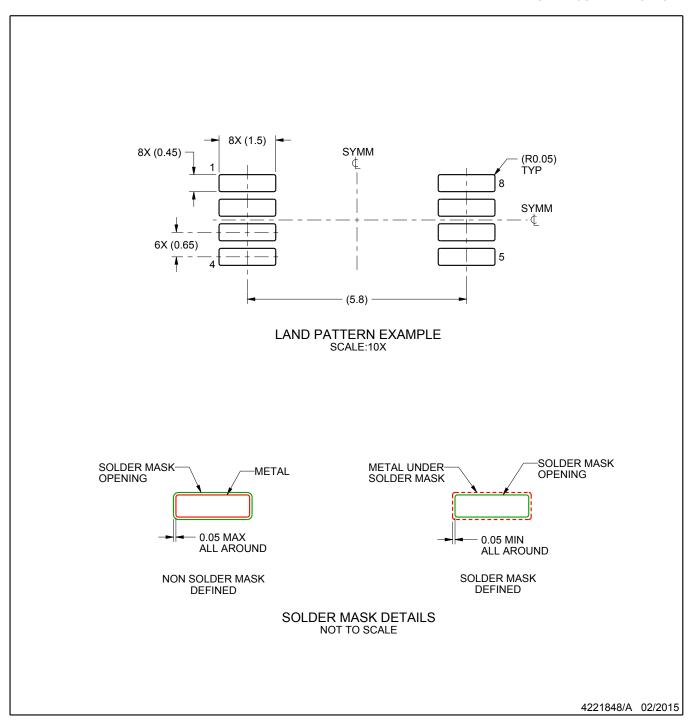
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



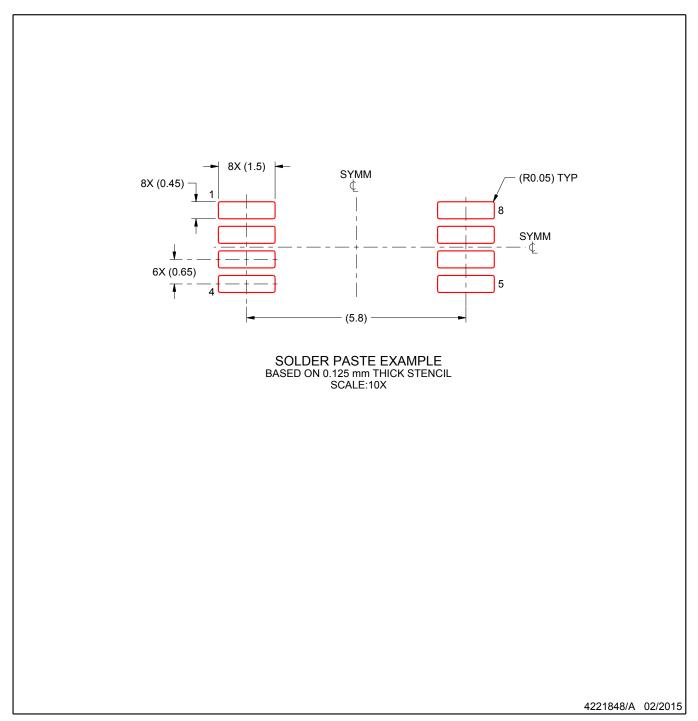
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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